NSN 5961-01-116-4489

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-116-4489 **Inclosure Material:** Ceramic and metal **Overall Length:** Between 0.960 inches and 0.990 inches **Overall Height:** Between 0.229 inches and 0.281 inches **Overall Width:** Between 0.720 inches and 0.730 inches **Mounting Facility Quantity: Internal Configuration:** Field effect **Mounting Method:** Unthreaded hole **Features Provided:** Burn in and hermetically sealed case and electrostatic sensitive **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 65.0 drain to source voltage and 65.0 drain to gate voltage and 40.0 gate to source voltage **Current Rating Per Characteristic:** 4.00 amperes drain current **Power Rating Per Characteristic:** 70.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No